74HC365; 74HCT365

Hex buffer/line driver; 3-state

Rev. 6 — 28 July 2021

Product data sheet

1. General description

The 74HC365; 74HCT365 is a hex buffer/line driver with 3-state outputs controlled by the output enable inputs ($\overline{\text{OEn}}$). A HIGH on $\overline{\text{OEn}}$ causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- · High noise immunity
- · Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Non-inverting outputs
- Input levels:
 - For 74HC365: CMOS level
 - For 74HCT365: TTL level
- · ESD protection:
- HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

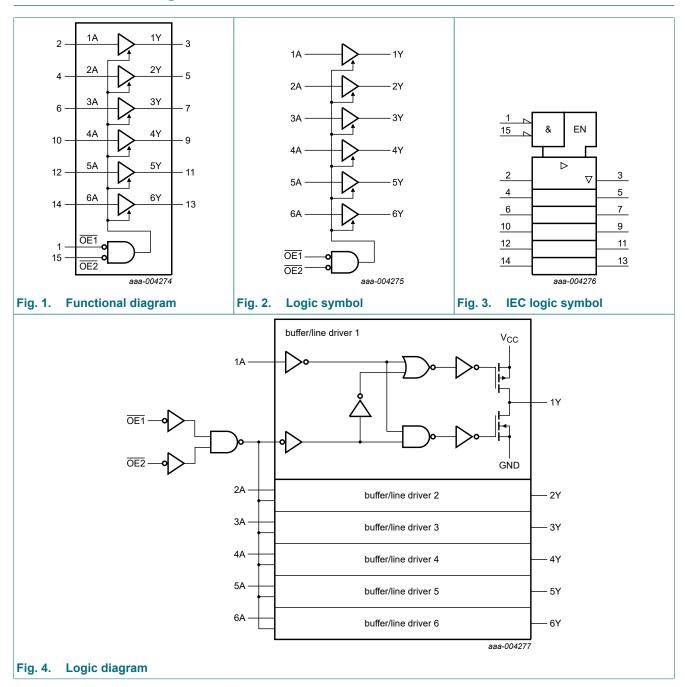
3. Ordering information

Table 1. Ordering information

Type number	Package			
Type Hulliber	rackaye			1
	Temperature range	Name	Description	Version
74HC365D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT365D	-			
74HC365PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT365PW	-		body width 4.4 mm	

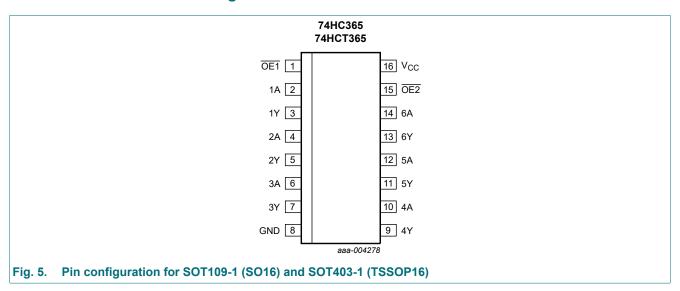


4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1	1	output enable input 1 (active LOW)
1A	2	data input 1
1Y	3	data output 1
2A	4	data input 2
2Y	5	data output 2
3A	6	data input 3
3Y	7	data output 3
GND	8	ground (0 V)
4Y	9	data output 4
4A	10	data input 4
5Y	11	data output 5
5A	12	data input 5
6Y	13	data output 6
6A	14	data input 6
ŌE2	15	output enable input 2 (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$

		Input	Output
OE1 OE2		nA	nY
L	L	L	L
L	L	Н	Н
X	Н	X	Z
Н	X	X	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
Io	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC365		74HCT365			Unit	
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

9. Static characteristics

Table 6. Static characteristics 74HC365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8		V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}	-	-	-	
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	- 0.5 1.35 1.8 	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.48	5.81	5.81 -	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μΑ
Icc	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μΑ
Cı	input capacitance		-	3.5	-	pF
T _{amb} = -	40 °C to +85 °C				'	•
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	1.35 1.8	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} = -4	10 °C to +125 °C		<u>'</u>		'	
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	· · · · · · · · · · · · · · · · · ·	V	
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

Table 7. Static characteristics 74HCT365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	4.5	-	V
		I _O = -6.0 mA	3.98	4.32	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0.1	V
		I _O = 6.0 mA	-	0.16	0.26	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	100	360	μΑ
		pin OE1	-	100	360	μΑ
		pin OE2	-	90	324	μΑ
Cı	input capacitance		-	3.5	-	pF
T _{amb} = -4	40 °C to +85 °C			•		•
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	8.0	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	- - - 0.1 0.26 ±0.1 ±0.5 8.0 360 360 324	V
		I _O = -6.0 mA	3.84	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	Ι _Ο = 20 μΑ	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$			±5.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	450	μΑ
		pin OE1	-	-	450	μΑ
		pin OE2	-	-	405	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +125 °C			'	1	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$				
		I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±10.0	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	-	490	μΑ
		pin OE1	-	-	490	μΑ
		pin OE2	-	-	441	μΑ

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC365

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C					'	
t _{pd}	propagation delay	nA to nY; see Fig. 6	[1]				
		V _{CC} = 2.0 V		-	30	95	ns
		V _{CC} = 4.5 V		-	11	19	ns
		V _{CC} = 5 V; C _L = 15 pF		-	9	-	ns
		V _{CC} = 6.0 V		-	9	16	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	47	150	ns
		V _{CC} = 4.5 V - 17 3	30	ns			
		V _{CC} = 6.0 V		-	14	26	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	61	150	ns
		V _{CC} = 4.5 V		-	22	30	ns
		V _{CC} = 6.0 V		-	18	26	ns
t	transition time	see Fig. 6	[4]				
		V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		- 5 12	12	ns	
		V _{CC} = 6.0 V		-	4	10	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to V_{CC}	[5]	-	40	-	pF

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -2	10 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; see Fig. 6	[1]				
		V _{CC} = 2.0 V		-	-	120	ns
		V _{CC} = 4.5 V		-	-	24	ns
		V _{CC} = 6.0 V		-	-	20	ns
t _{en}	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
t _t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	-	75	ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns
T _{amb} = -4	10 °C to +125 °C						
t _{pd}	propagation delay	nA to nY; see Fig. 6	[1]				
		V _{CC} = 2.0 V		-	-	145	ns
		V _{CC} = 4.5 V		-	-	29	ns
		V _{CC} = 6.0 V		-	-	25	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	-	90	ns
		V _{CC} = 4.5 V		-	-	18	ns
		V _{CC} = 6.0 V		_	_	15	ns

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

 t_{pd} is the same as t_{PHL} and t_{PLH} . t_{en} is the same as t_{PZH} and t_{PZL} .

^[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

t_{dis} is the same as t_{THL} and t_{TLH}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where:

Table 9. Dynamic characteristics 74HCT365

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						
t _{pd}	propagation delay	nA to nY; see Fig. 6	[1]				
		V _{CC} = 4.5 V		-	14	25	ns
		V _{CC} = 5 V; C _L = 15 pF		-	11	-	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[2]	-	18	35	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[3]	-	23	35	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	5	12	ns
C_{PD}	power dissipation capacitance	per buffer; V _I = GND to (V _{CC} - 1.5 V)	[5]	-	40	-	pF
T _{amb} = -	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see Fig. 6	[1]	-	-	31	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Fig. 7	[2]	-	-	44	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[3]	-	-	44	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	15	ns
T _{amb} = -4	40 °C to +125 °C						
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see Fig. 6	[1]	-	-	38	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[2]	-	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Fig. 7	[3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	18	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] \dot{t}_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PHZ} and $t_{\text{PLZ}}.$
- tdis is the same as t_{PHZ} and t_{PLZ}.
 t_t is the same as t_{THL} and t_{TLH}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where:
 f_i = input frequency in MHz;

f_o = output frequency in MHz;

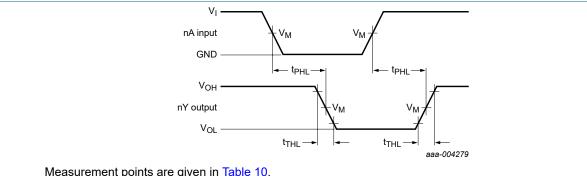
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

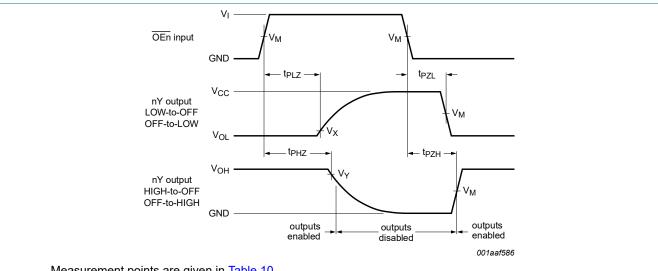
10.1. Waveforms and test circuit



Measurement points are given in Table 10.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. Propagation delay data input (nA) to output (nY) and output transition time



Measurement points are given in Table 10.

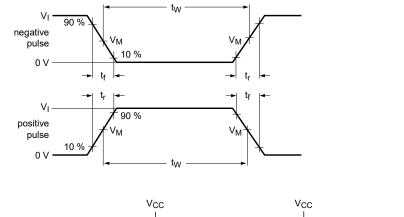
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

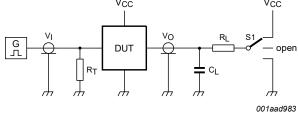
Fig. 7. 3-state enable and disable times

Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC365	0.5V _{CC}	0.5V _{CC}	0.1 × V _{CC}	0.9 × V _{CC}
74HCT365	1.3 V	1.3 V	0.1 × V _{CC}	0.9 × V _{CC}

11 / 17





Test data is given in Table 11.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

 C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance

S1 = Test selection switch

Fig. 8. Test circuit for measuring switching times

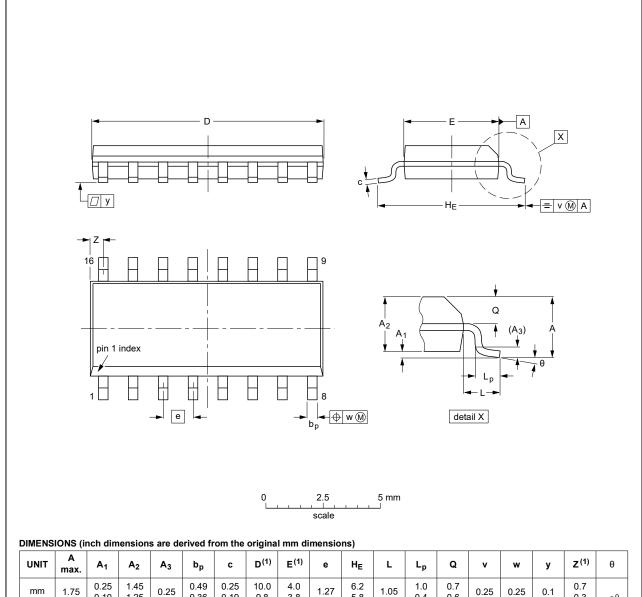
Table 11. Test data

Туре	Input		Load		S1 position			
	V_{l}	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t_{PZL}, t_{PLZ}	
74HC365	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74HCT365	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

11. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UN	IT ma		A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mr	n 1.1	75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inch	es 0.0	069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

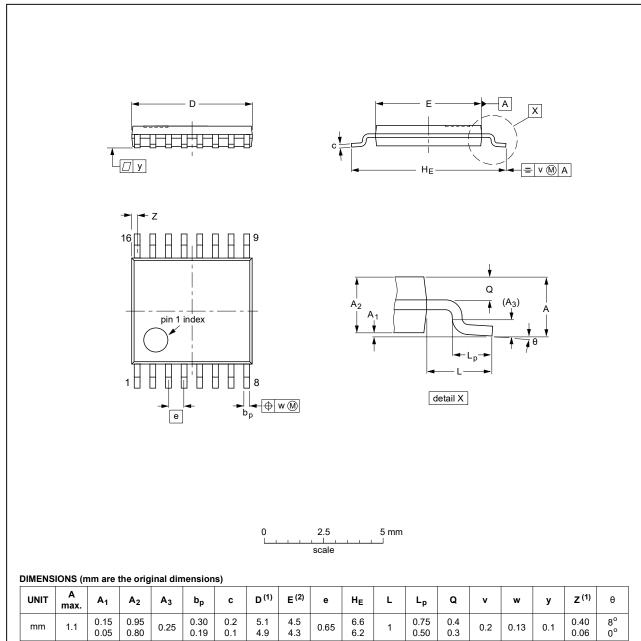
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig. 9. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT403-1		MO-153			99-12-27 03-02-18	

Fig. 10. Package outline SOT403-1 (TSSOP16)

14 / 17

12. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT365 v.6	20210728	Product data sheet	-	74HC_HCT365 v.5
Modifications:	Type number 7	74HCT365DB (SOT338-1/SSC	P16) removed.	
74HC_HCT365 v.5	20210212	Product data sheet	-	74HC_HCT365 v.4
Modifications:	Nexperia. Legal texts have Section 1 and Type number 7	we been adapted to the new constant of the new	ompany name where	appropriate.
74HC_HCT365 v.4	20160127	Product data sheet	-	74HC_HCT365 v.3
Modifications:	Type numbers	74HC365N and 74HCT365N	(SOT38-4) removed	
74HC_HCT365 v.3	20120905	Product data sheet	-	74HC_HCT365_CNV v.2
Modifications:	guidelines of N	His data sheet has been redes IXP Semiconductors. We been adapted to the new co		·
74HC_HCT365_CNV v.2	19970829	Product specification	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1.	General description	. 1
2.	Features and benefits	1
3.	Ordering information	. 1
4.	Functional diagram	.2
5.	Pinning information	. 3
5.1	. Pinning	. 3
5.2	Pin description	. 3
6.	Functional description	4
7.	Limiting values	4
8.	Recommended operating conditions	.4
9.	Static characteristics	.5
10.	Dynamic characteristics	8
10.	1. Waveforms and test circuit1	11
11.	Package outline1	13
12.	Abbreviations1	15
13.	Revision history1	15
14.	Legal information1	16

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 28 July 2021

17 / 17

[©] Nexperia B.V. 2021. All rights reserved